

Why holes are not like electrons. III. How holes in the normal state turn into electrons in the superconducting state

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In recent work, we discussed the difference between electrons and holes in energy band in solids from a many-particle point of view, originating in the electron-electron interaction[1], and from a single particle point of view, originating in the electron-ion interaction[2]. We proposed that superconductivity in solids only occurs when the Fermi level is close to the top of a band (hole carriers), that it originates in ‘undressing’ of carriers from *both* the electron-electron and the electron-ion interaction, and that as a consequence holes in the normal state behave like electrons in the superconducting state[3]. However, the connection between both undressing effects was left unclear, as was left unclear how the transformation from hole behavior to electron behavior occurs. Here we clarify these questions by showing that the same electron-electron interaction physics that promotes pairing of hole carriers and undressing of carriers from the electron-electron interaction leads to undressing of carriers from the electron-ion interaction and transforms the behavior of carriers from hole-like to electron-like. Furthermore this phenomenon is connected with the expulsion of negative charge that we predict to occur in superconductors. These unexpected connections support the validity of our theoretical framework, the theory of hole superconductivity, to explain superconductivity in solids.

PACS numbers:

I. INTRODUCTION

When Felix Bloch formulated his epoch-making theory of electrons in metals[4], he had an “uneasy feeling that the model of independent electrons might represent a rather poor approximation and would turn out *in some respects* to be entirely inadequate”[5] (italic ours). Bloch realized full well the arbitrariness involved in his privileging the electron-ion interaction over the direct electron-electron Coulomb interaction, given that $e^2 = 14.4eV\text{\AA}$ is just as large an interaction between two electrons as between an electron and a monovalent ion at the same distance[6]. In the statement quoted above, with “in some respects” Bloch had undoubtedly the phenomenon of superconductivity in mind[6], which was widely believed at the time to be caused by the electron-electron Coulomb interaction[7]. However, Bloch’s theory’s myopic point of view became even more myopic with the conventional theory of superconductivity[8], that adscribes the phenomenon to the interaction of electrons with ions displaced from their equilibrium position (electron-phonon interaction)[9], bringing the disregard for the role of the electron-electron Coulomb interaction to a new high.

Instead, the theory of hole superconductivity[10] proposes that while electron-electron Coulomb interactions can indeed be neglected when a band is almost empty, they become increasingly dominant as the filling of a band increases. Unlike the prevalent point of view nowadays, that electron-electron interactions are most important near half-filling of a band[11], we propose that electron-electron interaction physics dominates and *qualitatively* changes the normal metallic behavior *when*

an electronic energy band is almost full, in particular giving rise to superconductivity.

We propose that the normal metallic and the superconducting state are in a sense mirror images of each other, where the ‘mirror’ switches the sign of the electric charge, or the bottom and top of the band, or the electron-ion and the electron-electron interactions. The ‘mirror’ is by no means perfect because of the vastly different masses associated with the negative electron and the positive ion, hence there are significant differences between the normal metallic and the superconducting state, and the ‘mirror switching’ does not occur right at the half filled band but instead only when a band is almost full. Nevertheless, an essential commonality between both states emerges from considering the electron-ion and the electron-electron interaction on an equal footing, leading to the conclusion that normal metallic behavior ensues when the electron-ion interaction dominates, and superconducting behavior when the electron-electron interaction dominates.

In the normal metal, there are few electrons in the band with a lot of room to move around, the positive ions are rigid and the electrons will act as nearly independent of each other and adjust their wavefunctions *individually* to optimize the electron-ion interaction, with the electron-electron interaction being non-optimized. In the superconductor instead, the almost-full band is crowded with a lot of electrons that become ‘rigid’ because of their mutual strong interaction, with their wavefunction adjusted to optimize the electron-electron interaction and with the electron-ion interaction being non-optimized. This means in particular that states that are electron-ion-interaction-energy costly will be occupied in the superconducting state. A consequence of this point of view is also that the theory predicts that superconductivity

is particularly favored when the electron-ion interaction strength Ze^2 is weak, i.e. when the ionic charge Z is small[12].

In the following, we analyze that aspect of the Coulomb interaction that we believe to be essential to understand superconductivity, at the level of a single atom, a diatomic molecule and a solid. We show that the essential physics manifests itself in both real and momentum space in a remarkably parallel fashion in going from the atom to the solid. It involves *expansion* of the electronic wavefunction to achieve lowering of electron-electron interaction and of quantum kinetic energy, at the expense of electron-ion interaction energy.

II. THE ATOM

Consider the wavefunction of an electron in the lowest energy state (1s) of a hydrogen-like atom of nuclear charge Z

$$\varphi_Z(r) = \left(\frac{Z^3}{\pi}\right)^{1/2} e^{-Zr} \quad (1)$$

with r measured in units of the Bohr radius a_0 . For two electrons in the atom in a singlet state, the spatial wave function is *not*

$$\psi(r_1, r_2) = \varphi_Z(r_1)\varphi_Z(r_2) \quad (2)$$

because the strong Coulomb interaction between two electrons in this state

$$U = \int d^3r d^3r' |\varphi_Z(r_1)|^2 \frac{e^2}{|\vec{r}_1 - \vec{r}_2|} |\varphi_Z(r_2)|^2 \quad (3)$$

makes this state energetically too costly. The true wave function in the two-electron atom contains both radial and angular correlations between the electrons, and is well described by the Hylleraas wave function[13]. However, the main effect is captured by the Hartree approximation that allows for expansion of the single-particle orbital:

$$\psi_H(r_1, r_2) = \varphi_{\bar{Z}}(r_1)\varphi_{\bar{Z}}(r_2) \quad (4a)$$

with

$$\bar{Z} = Z - y \quad (4b)$$

The energy of the electrons in that state is (expressed in Rydbergs=13.6eV)

$$E(\bar{Z}) = E_{kin}(\bar{Z}) + E_{e-i}(\bar{Z}) + E_{e-e}(\bar{Z}) \quad (5)$$

with

$$E_{kin}(\bar{Z}) = 2\bar{Z}^2 = E_{kin}(Z) - 4Zy + 2y^2 \quad (6a)$$

$$E_{e-i}(\bar{Z}) = -4Z\bar{Z} = E_{e-i}(Z) + 4Zy \quad (6b)$$

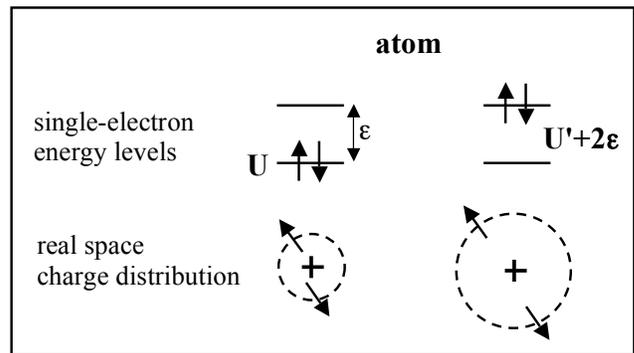


FIG. 1: The two-electron atom. When the two electrons occupy the unexpanded orbital, they pay a high price in Coulomb energy, U . Instead, they prefer to reside in an expanded orbital, paying each the price ϵ in single-particle energy, yet achieving a lower total energy $U' + 2\epsilon$.

$$E_{e-e}(\bar{Z}) = \frac{5}{4}\bar{Z} = E_{e-e}(Z) - \frac{5}{4}y \quad (6c)$$

with $E_{e-e}(Z) = U$. Therefore, expansion of the orbital *costs* electron-ion energy

$$\Delta E_{e-i} = 4Zy \quad (7a)$$

but gives a lowering of both kinetic energy

$$\Delta E_{kin} = -4Zy + 2y^2 \quad (7b)$$

and of Coulomb energy

$$\Delta E_{e-e} = -\frac{5}{4}y. \quad (7c)$$

The single-particle energy of each electron in the expanded orbital is the sum of its kinetic and electron-ion energy, and is *larger* than the single-particle energy in the unexpanded orbital by

$$\epsilon = \frac{1}{2}(\Delta E_{kin} + \Delta E_{e-i}) = y^2 \quad (8)$$

because the cost in electron-ion energy is larger than the kinetic-energy lowering. However, this is more than offset by the reduction in Coulomb repulsion in the expanded orbital:

$$U' \equiv E_{e-e}(\bar{Z}) = U - \frac{5}{4}y \quad (9)$$

so that the total energy

$$U' + 2\epsilon = U + 2y^2 - \frac{5}{4}y \quad (10)$$

is lower than the energy in the non-expanded doubly occupied orbital provided $y < 5/8$.

We represent the situation schematically in Fig. 1, with two “orbitals” per atom. The two electrons “choose” to occupy the orbital with higher single-particle

energy because the lower Coulomb repulsion more than offsets the cost in single-particle energy. The space-charge distribution becomes more extended in real space: negative charge is “expelled” outward when the second electron is added to the orbital, leading to the lowering of both electron-electron Coulomb energy (Eq. 7c) and kinetic energy (Eq. (7b)).

The optimal value of y that minimizes the energy Eq. (10) is $y = 5/16$, so the orbital Eq. (1) expands to $\varphi_{\bar{Z}}(r)$ with $\bar{Z} = Z - \frac{5}{16}$, which costs electron-ion Coulomb energy $\Delta E_{e-i} = \frac{5}{4}Z$ but gives a lowering of kinetic energy $\Delta E_{kin} = -\frac{5}{4}Z + \frac{25}{128}$ and of electron-electron Coulomb energy $\Delta E_{e-e} = -\frac{25}{64}$. The single-particle energy of each electron in the expanded orbital is larger than the single-particle energy in the unexpanded orbital by $\epsilon = \frac{25}{256}$ which is more than offset by the reduction in Coulomb repulsion in the expanded orbital $U' = U(Z - 5/16) = U(Z) - \frac{25}{64}$, so that the total energy is $U' + 2\epsilon = U - \frac{25}{128}$ and the energy lowering achieved by expanding the orbital is $25/128 Ry = 2.7 eV$.

The physics of the two-electron atom just described is a remarkable microcosm of the physics of electrons in a nearly filled electronic energy band: orbital expansion and promotion to higher single-particle energy levels driven by electron-electron repulsion and kinetic energy lowering will play a key role, as we discuss in the following sections.

III. THE DIATOMIC MOLECULE

Within a linear combination of atomic orbitals approach, the bonding and antibonding orbitals of a diatomic molecule are given by

$$\psi_{b,a}(r) = \frac{\varphi_1(r) \pm \varphi_2(r)}{(2(1 \pm S_{12}))^{1/2}} \quad (11)$$

with the + (−) sign corresponding to bonding (b) (antibonding (a)), assuming s-orbitals for definiteness. $S_{12} = (\varphi_1, \varphi_2)$ is the overlap matrix element. The bonding orbital has larger amplitude and correspondingly larger charge density in the region between the atoms, while the antibonding orbital changes sign and has vanishing charge density at a point between the atoms, as depicted in Fig. 2(a). As emphasized in II, this is a real physical difference between bonding and antibonding orbitals that cannot be eliminated by a canonical transformation.

Putting two electrons in the bonding orbital results in an electron-electron repulsion energy

$$\begin{aligned} U_{bb} &= \int d^3r d^3r' |\psi_b(r)|^2 \frac{e^2}{|\vec{r} - \vec{r}'|} |\psi_b(r')|^2 \\ &= \frac{U + V + 2J + 4\Delta t}{2(1 + S_{12})^2} \end{aligned} \quad (12a)$$

and for two electrons in the antibonding orbital

$$U_{aa} = \frac{U + V + 2J - 4\Delta t}{2(1 - S_{12})^2} \quad (12b)$$

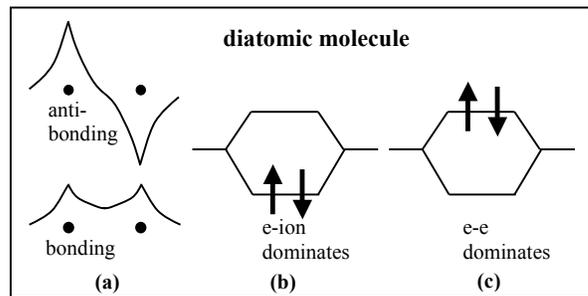


FIG. 2: (a) Schematic depiction of the wavefunction for bonding and antibonding orbitals in a diatomic molecule. The bonding orbital has higher charge density between the ions to get maximum benefit from the electron-ion interaction and a smooth wavefunction to give lower kinetic energy. (b) and (c) shows the bonding (lower) and antibonding (upper) single-particle energy levels, with different occupations of two electrons of opposite spin.

where, in terms of the Coulomb integrals

$$(ij|kl) \equiv \int d^3r d^3r' \varphi_i^*(r) \varphi_j^*(r') \frac{e^2}{|\vec{r} - \vec{r}'|} \varphi_l(r') \varphi_k(r) \quad (13)$$

$U = (ii|ii)$, $V = (ij|ij)$, $J = (ij|ji) = (ii|jj)$ and $\Delta t = (ii|ij)$. All these matrix elements are positive. In particular, the hybrid Coulomb matrix element

$$\Delta t = (ii|ij) \quad (14)$$

lowers the Coulomb repulsion for two electrons in antibonding states[15], as seen from Eq. (12b). For sufficiently large Δt , the ‘inverted occupation’ shown in Fig. 2(c) with the two electrons in the antibonding orbital would have lower total energy (kinetic + electron-ion + electron-electron) than the usual one where both electrons are in the bonding orbital, Fig. 2(b).

Note also that for one electron in the bonding state and one in the antibonding state, the direct Coulomb repulsion is

$$U_{ba} = \frac{U + V - 2J}{2(1 - S_{12}^2)} \quad (15)$$

which indicates that the Coulomb matrix element J favors ferromagnetism, particularly near the half-filled band[14].

Let us now consider the diatomic molecule as a microcosm for an electronic energy band, as depicted in Fig. 3. If the electron-ion energy dominates, the occupation will be as shown on the left side. In particular, for three electrons in the molecule (analogous to a ‘nearly filled band’) two electrons will go into the bonding state and one electron into the antibonding state. Instead, if the electron-electron interaction dominates, the occupation will be as depicted on the right side of Fig. 3, where two electrons occupy the antibonding state and one electron the bonding state. Equivalently, *the single hole in*

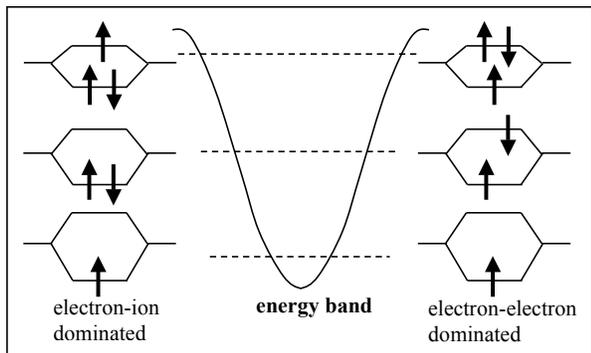


FIG. 3: The diatomic molecule as a microcosm for an energy band. When the electron-electron interaction dominates, the occupation of single-particle energy levels changes, as shown on the right side of the figure: the middle diagram represents a ferromagnet and the upper diagram a superconductor.

the filled band resides in the bonding rather than in the antibonding state.

In a tight binding description, the Hamiltonian for electrons in a diatomic molecule with one orbital per atom is given by[16]

$$H = - \sum_{\sigma} [t_0 - \Delta t(n_{1,-\sigma} + n_{2,-\sigma})] + U \sum_i n_{i\uparrow} n_{i\downarrow} + V \sum_{\sigma} n_{1\sigma} n_{2\sigma} + J \left(\sum_{\sigma} (c_{1\sigma}^{\dagger} c_{2\sigma} + h.c.) \right)^2 \quad (16)$$

assuming higher order interactions (involving 6 or more fermion operators) can be neglected. t_0 is the hopping amplitude for a single electron in the molecule. The creation and annihilation operators in Eq. (16) refer to *orthogonal orbitals* $\phi_1(r), \phi_2(r)$ obtained from linear combinations of the atomic orbitals $\varphi_1(r), \varphi_2(r)$ [16]. The Coulomb matrix elements are given by the expression Eq. (13) with the orthogonal orbitals. In particular, the hybrid matrix element Δt is given in terms of Eq. (13) with atomic orbitals, $\Delta t_{a.o.}$, by

$$\Delta t = \Delta t_{a.o.} - \frac{S_{12}}{2}(U + V) \quad (17)$$

to lowest order in the nearest neighbor overlap S_{12} . To the extent that the Mulliken approximation for the overlap charge distribution holds[17], the expression Eq. (17) exactly vanishes, and in practice it is found that deviations from the Mulliken approximation are very small[16]. For that reason, the "correlated hopping" interaction term Δt is usually ignored in formulating tight binding Hamiltonians to describe interacting electrons in solids.

However, in considering the interactions between electrons as the number of electrons in the diatomic molecule (or the band) increases it is essential to take into account the expansion of the atomic orbital that occurs for the doubly-occupied atom, discussed in Sect. II. When doing so, we showed in Refs. [12, 18, 19] that the correlated hopping term Δt has a value very different from that

given by Eq. (17): it is increasingly positive as the interatomic distance R decreases and the ionic charge Z decreases. The 'correlated hopping' parameter Δt changes the hopping amplitude depending on the electronic occupation of the sites involved in the hopping process: the hopping amplitude for an electron is $t_0, t_0 - \Delta t$ and $t_0 - 2\Delta t$ depending on whether there are 0, 1 or 2 other electrons at the sites involved in the hopping process.

For one electron in the diatomic molecule, the eigenstates of the Hamiltonian Eq. (16) are the bonding and antibonding states $c_{b\sigma}^{\dagger}|0\rangle, c_{a\sigma}^{\dagger}|0\rangle$, with $|0\rangle$ the empty molecule and

$$c_{b\sigma}^{\dagger} = \frac{c_{1\sigma}^{\dagger} + c_{2\sigma}^{\dagger}}{\sqrt{2}} \quad (18a)$$

$$c_{a\sigma}^{\dagger} = \frac{c_{1\sigma}^{\dagger} - c_{2\sigma}^{\dagger}}{\sqrt{2}} \quad (18b)$$

and energies $\epsilon_b = -t_0, \epsilon_a = +t_0$. For three electrons in the molecule, the eigenstates are

$$|\tilde{b}\rangle_{\sigma} = c_{a\sigma}^{\dagger} c_{b\uparrow}^{\dagger} c_{b\downarrow}^{\dagger} |0\rangle \quad (19a)$$

$$|\tilde{a}\rangle_{\sigma} = c_{a\uparrow}^{\dagger} c_{a\downarrow}^{\dagger} c_{b\sigma}^{\dagger} |0\rangle \quad (19b)$$

with energies

$$\tilde{\epsilon}_b = -(t_0 - 2\Delta t) + U + 2V \quad (20a)$$

$$\tilde{\epsilon}_a = +(t_0 - 2\Delta t) + U + 2V \quad (20b)$$

respectively. The ordering of these states depends on the magnitude of the single hole hopping amplitude

$$t_h \equiv t_0 - 2\Delta t \quad (21)$$

For $t_h > 0$, $\tilde{\epsilon}_b < \tilde{\epsilon}_a$ and the state $|\tilde{b}\rangle_{\sigma}$, corresponding to two electrons in the bonding orbital and one electron in the antibonding orbital has lower energy than the state $|\tilde{a}\rangle_{\sigma}$, so the lowest energy state corresponds to the three-electron state on the left side of Fig. 3. Instead, for $t_h < 0$ the ordering is reversed and two electrons will occupy the antibonding orbital, as depicted on the right side of Fig. 3. The latter situation will occur if $\Delta t > t_0/2$.

The parameter Δt represents a 'bond charge repulsion'[20] between electrons: it pushes electrons away from the bond (region between the ions) towards the sites (ions) by suppressing the occupation of the bonding state and increasing the occupation of the antibonding state. The magnitude of the hopping parameter t_0 , which is determined by the strength of the electron-ion attraction, decreases as the ionic charge Z decreases. Instead, as already mentioned, the magnitude of Δt *increases* as the ionic charge decreases because of the increased orbital expansion under double occupancy. So when the

electron-electron interaction dominates over the electron-ion attraction in the diatomic molecule, t_h changes sign and this leads to the inverted occupation shown on the right side of Fig. 3.

Furthermore, as the electrons doubly-occupy the antibonding orbital, they have larger amplitude for their wavefunction at the atomic site, rather than in the interatomic bond, as depicted by the upper picture in Fig. 2(a). Larger on-site occupation implies a larger expansion of the atomic wavefunction, as depicted in the lower right panel of Fig. 1, and hence negative charge is expelled *outward*, away from the interatomic region. This in turn also causes a relative lowering of kinetic energy, as discussed in Sect. II for the single atom.

In summary, our analysis of the diatomic molecule shows strong parallels with the discussion in Sect. II for the single atom: when the electron-electron interaction dominates over the electron-ion interaction, the single-electron higher energy level (antibonding state) becomes more occupied and the single-electron lower energy level (bonding state) becomes less occupied. In other words, holes tend to increasingly occupy the lower-energy single-electron energy levels. At the same time, the negative charge spatial distribution increases *outward*, which implies a higher positive charge distribution in the region inside the structure. That is, negative charge is “expelled” from the interior region of the molecule towards the exterior. The interaction matrix element responsible for this effect in the diatomic molecule (and in the solid as we will see) is Δt , and the essential underlying physics is orbital expansion driven by electron-electron interaction (since, as mentioned, in the absence of orbital expansion the parameter Δt is found to be zero) and kinetic energy lowering (since the atomic orbital expansion gives kinetic energy lowering as seen in Sect. I).

IV. FURTHER ANALYSIS OF Δt

In this section we discuss in more detail the physical origin of the occupation inversion that we argue can occur in the diatomic molecule, because the same principles will apply to the solid state. In Refs. [12, 18, 19] we calculated from first principles the hopping amplitude for a single electron, t_0 , and for a single hole, t_h , in a diatomic molecule, taking into account the orbital relaxation effect. These hopping amplitudes were obtained from the difference in energy of an electron or a hole in the bonding and antibonding states. As can be seen for example in Fig. 7(c) of Ref. [19], the hole hopping amplitude t_h (denoted by t_2 in ref.[19]) goes to zero *and in fact changes sign* for sufficiently small interatomic distance R and small ionic charge Z . In this section we discuss in more detail how the change in sign of t_h comes about.

In paper I of this series[1] we have emphasized the change in hopping amplitude with occupation that arises from the overlap matrix element of the expanded and unexpanded atomic orbital. For the 1s orbital discussed in

sect. II, the atomic overlap matrix element is given by

$$S = (\varphi_Z, \varphi_{\bar{Z}}) = \frac{(Z\bar{Z})^{3/2}}{(\frac{Z+\bar{Z}}{2})^3} \quad (22)$$

with $\bar{Z} = Z - 5/16$. S is a decreasing function of the ionic charge Z , and as $Z \rightarrow 5/16$ it becomes arbitrarily small. The hopping amplitude for an electron when there are m other electrons in the two sites involved in the hopping process is $t_m = S^m t_0$, and has the same sign as t_0 . If we define Δt as the difference in hopping amplitude for a single hole and when there is a second hole in one of the sites, it is given by

$$\Delta t = t_0 S(1 - S) \quad (23)$$

This physics will promote pairing of hole carriers[21], but will *not* change the sign of the hopping amplitude for holes, since for a single hole we have

$$t_h = t_0 S^2 \quad (24)$$

of the same sign as t_0 .

However, there are additional contributions to the variation of hopping amplitude with occupation, that arise from matrix elements of the Coulomb interaction involving electrons on neighboring sites. In the absence of orbital expansion these contributions essentially cancel, as discussed in Sect. III, however in combination with orbital expansion they have a fundamental effect, and Eq. (24) ceases to be correct. We discussed in Ref.[12] a calculation of the hopping amplitude for a single hole in the diatomic molecule obtained by approximating the bonding and antibonding states of the three-electron diatomic molecule by the wavefunction

$$\tilde{\psi}_{b,a}(r_1, r_2, r_3) = \frac{\bar{\varphi}_1(r_1)\bar{\varphi}_1(r_2)\varphi_2(r_3) \pm \varphi_1(r_1)\bar{\varphi}_2(r_2)\bar{\varphi}_2(r_3)}{(2(1 \pm \tilde{S}_{12}))^{1/2}} \quad (25)$$

where $\bar{\varphi}_i(r_j)$ and $\varphi_i(r_j)$ are the expanded and unexpanded orbitals for the j -th electron in atom $i = 1, 2$ and the overlap is

$$\tilde{S}_{12} = (\bar{\varphi}_1, \varphi_1)^2 (\bar{\varphi}_1, \varphi_2). \quad (26)$$

where $(\bar{\varphi}_1, \varphi_1) = S$ (Eq. (22)). The energies of these states are

$$\tilde{\epsilon}_{b,a} = \frac{(\bar{1}\bar{1}2|H_3|\bar{1}\bar{1}2) \pm (\bar{1}\bar{1}2|H_3|1\bar{2}\bar{2})}{1 \pm \tilde{S}_{12}} \quad (27)$$

where the labels 1, $\bar{1}$ are shorthand for the orbitals $\varphi_1, \bar{\varphi}_1$, etc. The three-electron Hamiltonian is given by

$$H_3 = H_{3sp} + H_{3ee} \quad (28a)$$

with the single-particle and electron-electron parts given by

$$H_{3sp} = h_1 + h_2 + h_3 \quad (28b)$$

$$H_{3ee} = h_{12} + h_{23} + h_{13} \quad (28c)$$

where h_i is the single-particle Hamiltonian for the i -th electron and h_{ij} the interaction potential between the i -th and j -th electron, given by (in atomic units)

$$h = -\nabla^2 - \frac{2Z}{r_1} - \frac{2Z}{r_2} \quad (29a)$$

$$h_{12} = \frac{2}{r_{12}} \quad (29b)$$

with r_1, r_2 the electronic coordinate relative to atom 1, 2, and r_{12} the distance between electrons. The difference between the energies Eq. (27) give the hole hopping amplitude t_h

$$t_h = \frac{\tilde{\epsilon}_a - \tilde{\epsilon}_b}{2}. \quad (30)$$

In the regime where the overlap S is small (small ionic charge Z) we can neglect the overlap Eq. (26), being proportional to S^2 . The difference in energies between the bonding and antibonding states is then determined by the second matrix element in Eq. (27), given by

$$(\bar{1}\bar{1}\bar{2}|H_3|1\bar{2}\bar{2}) = (\bar{1}\bar{1}\bar{2}|H_{3sp}|1\bar{2}\bar{2}) + (\bar{1}\bar{1}\bar{2}|H_{3ee}|1\bar{2}\bar{2}) \quad (31)$$

The first term in Eq. (31) (single-particle term) is

$$(\bar{1}\bar{1}\bar{2}|H_{3sp}|1\bar{2}\bar{2}) = (\bar{1}, h, \bar{2})S^2 + 2(\bar{1}, h, \bar{1})SS_{1\bar{2}} \quad (32)$$

and is negative, so it lowers the energy of the bonding state and raises the energy of the antibonding state. The first term in Eq. (32) corresponds essentially to Eq. (24), the second term would be absent if the orbitals at neighboring sites were constructed to be orthogonal to each other.

The second term in Eq. (31) (electron-electron interaction term) is

$$(\bar{1}\bar{1}\bar{2}|H_{3ee}|1\bar{2}\bar{2}) = 2(\bar{1}, \bar{1}, h_{12}, 1, \bar{2})S + (\bar{1}, 2, h_{12}, 1, \bar{2})S_{1\bar{2}} \quad (33)$$

and is positive, so it raises the energy of the bonding state and lowers the energy of the antibonding state. It is clear then that the state of inverted occupation (antibonding state) has lower electron-electron interaction energy than the ordinary state (bonding state). The difference in energy between the states is the hole hopping amplitude

$$t_h = -(\bar{1}, h, \bar{2})S^2 - 2(\bar{1}, h, \bar{1})SS_{1\bar{2}} - 2(\bar{1}, \bar{1}, h_{12}, 1, \bar{2})S - (\bar{1}, 2, h_{12}, 1, \bar{2})S_{1\bar{2}} \quad (34)$$

where the first two terms, involving the electron-ion interaction, are positive (including their sign), and the last two terms involving the electron-electron interaction are negative (including their sign). When the electron-electron interaction dominates over the electron-ion interaction (for small ionic charge Z) the sign of t_h switches

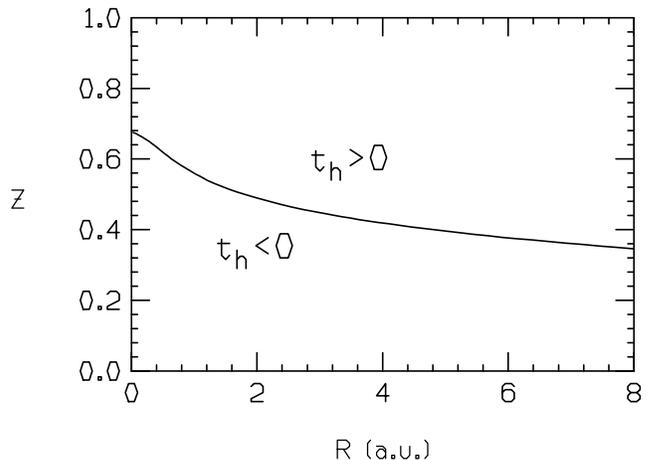


FIG. 4: Dependence of the sign of the single hole hopping amplitude in the diatomic molecule t_h on the ionic charge Z and the interatomic distance R for the $1s$ orbital. In the region above the curve the single hole hopping amplitude has the same sign as the single electron hopping amplitude t_0 ($t_0 > 0$), corresponding to the ordering of energy levels shown on the left side of Fig. 3. In the region below the curve the sign of the single hole hopping amplitude is opposite to that of the single electron hopping amplitude and the occupation of the levels for three electrons in the diatomic molecule is inverted as shown on the right side of Fig. 3.

from positive to negative, and the state of inverted occupation becomes the low-energy state.

In Ref.[12] we only explored the parameter regime where t_h has the same sign as t_0 , i.e. where there is no occupation inversion. For sufficiently small Z and small interatomic distance R , t_h is found to change sign, as shown in Fig. 4. (For the calculation in Fig. 4 the overlap Eq. (26) was included hence there are other terms in t_h beyond those given in Eq. (34), see Ref.[12]). The region $t_h < 0$ corresponds to the electron-electron dominated regime shown on the right side of Fig. 3, where occupation inversion occurs. For further details on the form of the matrix elements entering in the calculation leading to Fig. 4 the reader is referred to the Appendix of Ref.[12].

V. THE SOLID

We consider the Hamiltonian for electrons in a band in a tight binding representation given by[15]

$$H = - \sum_{\langle ij \rangle, \sigma} (t_0 - \Delta t(n_{i, -\sigma} + n_{j, -\sigma})) (c_{i\sigma}^\dagger c_{j\sigma} + h.c.) + U \sum_i n_{i\uparrow} n_{i\downarrow} + V \sum_{\langle ij \rangle} n_i n_j \quad (35)$$

Performing a particle hole transformation

$$h_{i\sigma}^\dagger = c_{i\sigma} \quad (36)$$

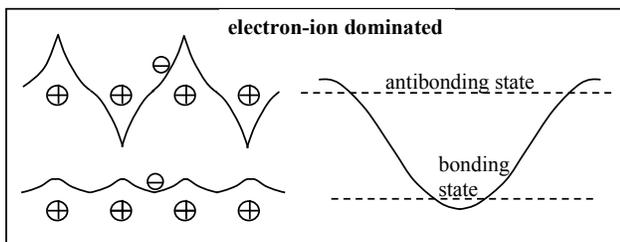


FIG. 5: The electronic states at the Fermi energy look very different when the Fermi level is near the bottom and near the top of a band in a normal metal. Near the bottom of the band the wavelength is large and the state is smooth, resembling the free-electron plane wave function, nearly unaffected by the electron-ion potential. Instead, near the top of the band the wavelength approaches a single lattice spacing and the state is strongly modified by the electron-ion interaction.

the Hamiltonian becomes

$$H = + \sum_{\langle ij \rangle, \sigma} (t_h + \Delta t(n_{i,-\sigma} + n_{j,-\sigma})) (h_{i\sigma}^\dagger h_{j\sigma} + h.c.) + U \sum_i n_{i\uparrow} n_{i\downarrow} + V \sum_{\langle ij \rangle} n_i n_j \quad (37)$$

where the number operators are now $n_{i\sigma} = h_{i\sigma}^\dagger h_{i\sigma}$ and

$$t_h = t_0 - 2\Delta t. \quad (38)$$

We have shown that this Hamiltonian leads to pairing of holes and to superconductivity in a BCS formalism in the regime of low hole concentration[21]. Furthermore we have discussed that the transition to superconductivity driven by Δt is associated with ‘undressing’[22]: the effective mass of the carriers decreases and the quasiparticle weight increases, and a transfer of spectral weight from high to low frequencies takes place both in the single particle spectral function (detectable in photoemission experiments) and in the optical absorption spectrum[23].

In addition, in paper II of this series we have argued that superconductivity is also associated with ‘undressing’ of carriers from the electron-ion interaction, and that it involves a *wavelength expansion*: the wavelength of carriers at the Fermi energy grows from a microscopic length ($k_F^{-1} \sim \text{\AA}^{-1} \sim$ interatomic distance) to a much larger wavelength. Here we explain how this occurs.

Figure 5 shows schematically the form of the wavefunction of the carriers at the Fermi energy when the band is almost empty and when it is almost full. We are assuming that the hopping amplitude t_0 is positive, as occurs for s orbitals, which implies that the minimum in the band occurs for $k = 0$. When the Fermi level is close to the top of the band (hole carriers) the state is ‘bumpy’ rather than smooth. As discussed in II, it is not a state well-suited to conduct electricity: it is strongly coupled to the lattice and is (nearly) Bragg-scattered by it, transferring the momentum it acquires from an external field to the ionic lattice in the process, and acquiring momentum in opposite direction. It is highly ‘dressed’ by the

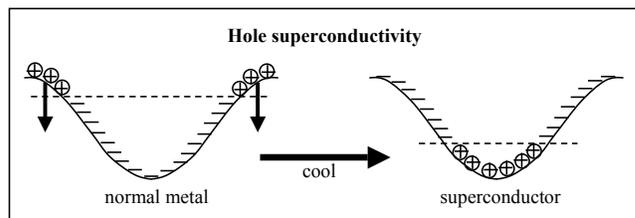


FIG. 6: When the system goes superconducting, the anti-bonding states near the top of the band become fully occupied with electrons and the bonding states at the bottom of the band become empty. In other words, the holes ‘Bose-condense’ to the bottom of the band. The promotion of electrons to the higher electron-ion energy states is driven principally by the electron-electron interaction.

electron-ion interaction. In addition, as discussed in I, as the hole propagates it causes a large deformation in the atomic cloud where it lands (Fig. 1), and as a consequence it is also highly dressed by the electron-electron interaction.

As the system goes superconducting the carriers at the Fermi energy undress from both the electron-electron[1] and the electron-ion interaction[2] in order to conduct better. Their wavelength expands, and they no longer ‘see’ the discrete electron-ion potential[2]. *Figure 6 illustrates how this occurs.*

Indeed, we propose that in the transition to superconductivity, the electronic occupation of the band is shifted upward, to occupy all the single-particle energy levels up to the top of the band, leaving the lowest energy levels in the band empty. In other words, the holes that were occupying the uppermost electronic levels ‘Bose-condense’ and now occupy the lowest electron-ion energy levels. By so doing, the electronic states that are now at the boundary between occupied and empty states (dashed line on the right side of Fig. 6) become ‘smooth’ states, of the ‘bonding type’, with large amplitude in the region between the ions[24].

How can such complete reorganization take place? Just like in the diatomic molecule, it will occur for low hole concentration if the hopping amplitude $t(n)$ (n =number of electrons per site) changes sign:

$$t(n) = t_0 - n\Delta t < 0 \quad (39)$$

so that in particular the single hole hopping amplitude $t_h = t_0 - 2\Delta t < 0$. Then, in the Hamiltonian Eq. (37) the lowest energy state for a hole occurs for $k = 0$ rather than for $k = \pi$. This, however, is not just a ‘canonical transformation’: the states near the bottom and the top of the band are *qualitatively* different.

As function of temperature, the hopping amplitude $t(n)$ can change sign if the number of electrons n increases as the temperature is lowered. Indeed we showed in Ref. [25] that several anomalous properties of high T_c cuprates are explained by the assumption that the number of holes in the $Cu - O$ planes decreases as the

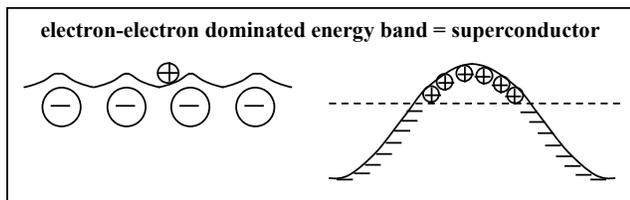


FIG. 7: In the superconducting state, the holes occupy smooth bonding states, that were previously occupied by electrons in the normal state. The holes ‘ride’ on top of the rigid negatively charged ions without disturbing their charge distribution as they do in the normal state[24]. The *electron* energy band depicted on the right side includes the electron-electron interaction energy $n\Delta t$ and therefore it is inverted.

temperature is lowered, and that such a charge transfer process between the planes and off-plane charge reservoir atoms is aided by the Coulomb matrix element Δt . In other systems the change in n with temperature may be associated with redistribution of occupation between different bands without charge transfer between different regions in real space.

In Figure 7 we represent the situation in an alternative way, where the ‘energy band’ now includes the electron-electron interaction energy $n\Delta t$. Because the sign of the hopping amplitude has changed for the almost-full band, the lowest energy electronic states occur at $k = \pi$ and are occupied by electrons, and the highest occur at $k = 0$ and are unoccupied. Because the band is almost full, the carriers at the Fermi energy now have a smooth wavefunction, as depicted on the left side of Fig. 7, just like the smooth wavefunction of carriers at the Fermi energy in the normal state of a metal when the band is almost empty. The holes ride ‘on top’ of the negative ions, without disturbing them and without noticing the discreteness of the potential. This corresponds to the ‘mirror image’ of the lower left panel of Fig. 5.

This reorganization in energy level occupation has a counterpart in the real space charge distribution. Figure 8 shows the situation schematically for the atom, the diatomic molecule and the solid. As higher single-electron energy levels become occupied, electronic charge moves *outward* in the three cases. The theory of hole superconductivity predicts that negative charge is expelled from the interior of the metal towards the surface as it undergoes the transition to the superconducting state[26], and that as a consequence an excess negative charge density ρ_- exists within a London penetration depth of the surface of superconductors, with $\rho_- = -H_c/4\pi$ or $\rho_- = -H_{c1}/4\pi$ for type I and type II superconductors respectively[27].

The superconductor looks like a ‘giant atom’[28] with expanded orbitals.

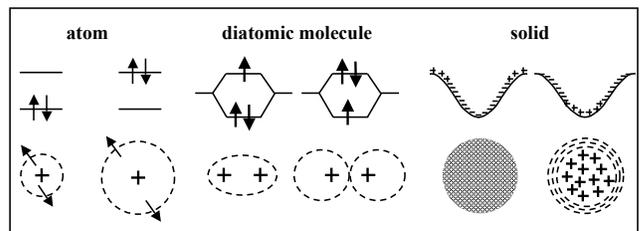


FIG. 8: Single-electron energy levels (upper part of the figure) and real space charge distribution (lower part of the figure). As electrons move up the energy levels, negative charge moves *outward* in the atom, the diatomic molecule and the solid in the superconducting state. In the solid in the normal state, the charge distribution is spatially homogeneous. The charge redistribution is driven by electron-electron repulsion and kinetic energy lowering, and is larger for smaller ionic charge Z in all three cases.

VI. SUPERCONDUCTIVITY FROM HOLE UNDRRESSING

As discussed in II and Ref. [3], there is plenty of experimental evidence that dressed *hole* carriers in the normal state become undressed from the electron-ion interaction and behave like undressed *electron* carriers in the superconducting state. How this occurs becomes clear from the considerations in this paper.

Let us review the experimental evidence for undressing of carriers from the electron-ion interaction in the superconducting state:

(1) *Rotating superconductor*: A superconducting body rotating with angular velocity $\vec{\omega}$ develops a uniform magnetic field in the interior[29], given by

$$\vec{B} = -\frac{2m_e c}{e} \vec{\omega} \quad (40)$$

with m_e the *free electron mass*. This has been measured in conventional, heavy fermion, and high T_c cuprate superconductors[30]. The magnetic field always points *parallel* to the angular velocity, as given by Eq. (40), never antiparallel, indicating that the superfluid carriers behave as *negatively charged carriers*[31].

(2) *Gyromagnetic effect*: If a magnetic field \vec{B} is suddenly applied to a superconductor at rest, the entire body is found to start rotating with angular momentum

$$\vec{L}_{body} = \frac{m_e c}{2\pi e} V \vec{B} \quad (41)$$

with m_e the free electron mass, and V the volume[32]. This angular momentum is always *antiparallel* to the applied magnetic field for the same reason as in (1) above[31].

(3) *Bernoulli potential*: Where there is a spatial variation of the superfluid velocity an electric field is expected to develop, the resulting potential is termed Bernoulli potential[33]. Experimental measurements[34] are con-

sistent with an electric field given by

$$\vec{E} = \frac{1}{e} \vec{\nabla} \frac{1}{2} m_e v_s^2 \quad (42)$$

where e and m_e are the *free electron* charge and mass, and v_s is the superfluid velocity. In particular the *sign* of the Bernoulli potential measured corresponds to *negative* charge carriers.

(4) *Hall effect*: The Hall coefficient is found to be essentially always positive in the normal state, corresponding to hole carriers[35], and to change its sign from positive to negative at temperatures slightly below T_c , indicating that carriers change from hole-like to electron-like[36].

(5) *Wavelength expansion*: We have proposed an explanation for the Meissner effect in superconductors involving a *wavelength expansion* of the carriers at the Fermi energy[2, 37] from the microscopic length k_F^{-1} to the mesoscopic length $2\lambda_L$ (λ_L =London penetration depth), corresponding to the wavevector change $k_F \rightarrow q_0 = 1/(2\lambda_L)$.

These experimental observations and theoretical considerations indicate that the carriers of electric current in the normal state, dressed hole carriers, morph into undressed electron-like carriers in the superconducting state. How does this happen? In II and Ref.[3], we suggested that the antibonding electrons at the top of the Fermi distribution in the normal state condense to the bottom of the band in the transition to superconductivity. However, this would conflict with the Pauli principle, because the states at the bottom of the band are occupied!

Furthermore, it is important to point out that it would be incorrect to assume that *all* the electrons in the band become ‘undressed’ from the electron-ion interaction in the superconducting state. Because the superfluid weight n_s that enters into the London penetration depth λ_L

$$\frac{1}{\lambda_L^2} = \frac{4\pi n_s e^2}{m_e c^2} \quad (43)$$

most definitely corresponds to the *hole* concentration rather than to the electron concentration in the band (which is much larger). It is essentially the same charge carrier density that carries the current in the normal state.

So the *holes* in the normal state have to behave *like electrons* in the superconducting state. The solution of this puzzle is what was depicted in Fig. 6. In Fig. 9 we show the expected evolution with temperature of the occupations in the band structure and in the Brillouin zone. As the metal is cooled into the superconducting state, the holes condense to the bottom of the band, which corresponds to long-wavelength states near the center of the Brillouin zone, which are smooth bonding states as depicted on the left side of Fig. 7. So it may be said that the superfluid carriers are still holes, not electrons. However, *the sign of the effective mass for carriers at the*

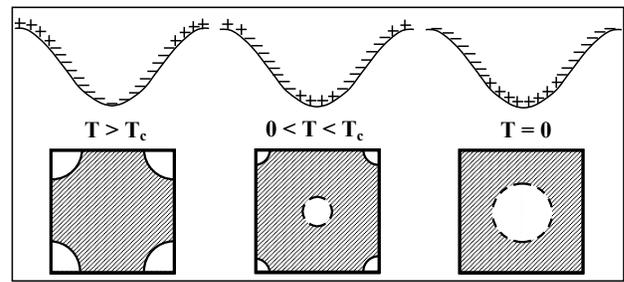


FIG. 9: Occupied states in the band (upper part of the figure) and in the Brillouin zone (lower part of the figure) as the temperature is lowered. The shaded areas of the Brillouin zone are occupied by electrons. When the temperature is lowered below T_c a ‘hole pocket’ is pierced at $k \sim 0$ that grows as the temperature is further lowered, while the hole pockets near the edges of the Brillouin zone become progressively smaller and eventually disappear at $T = 0$. At temperatures $0 < T < T_c$ the empty states near $k \sim \pi$ correspond to the normal fluid hole carriers and the empty states near $k \sim 0$ correspond to the superfluid hole carriers.

bottom of the band is opposite to that of carriers at the top of the band. For that reason, these superfluid hole carriers behave like electrons, and in particular exhibit a negative Hall coefficient, as well as the other signatures of electron transport reviewed at the beginning of this section.

Figure 9 also suggests a new interpretation of the ‘two-fluid model’[38] of superconductivity. The normal quasiparticles are the holes near the top of the band, i.e. $k \sim \pi$, while the superfluid are the holes at the bottom of the band, with $k \sim 0$. The conventional BCS theory is argued to be consistent with the two-fluid model[39], however it does not provide a clear separation of both components as Fig. 9 does.

Note also that the continuous process by which the holes move from the top to the bottom of the band as the superfluid condensate develops represents the momentum space counterpart of the orbit expansion discussed in connection with the Spin Meissner effect[37].

VII. TWO-ORBITAL MODEL

In previous work we have introduced an electronic model with two orbitals per site to describe the essential physics of electron-hole asymmetry (electronic dynamic Hubbard model)[40]. The spacing between single-particle energy levels is ϵ , and the interactions are such that two electrons will occupy predominantly the higher single-particle level because the Coulomb repulsion there (U') is much smaller than both in the lower level and between one electron in each level. This corresponds to the situation depicted schematically on the right side of Fig. 1.

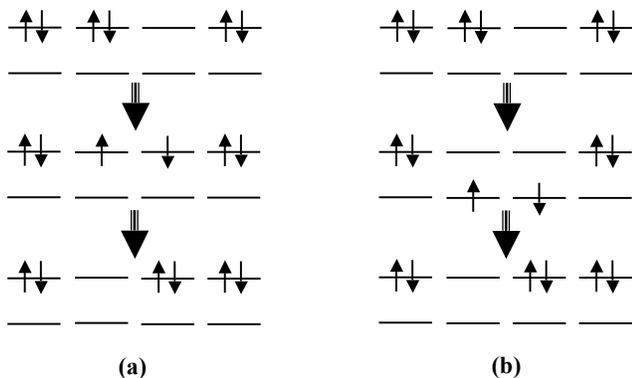


FIG. 10: Propagation of a pair in the strong coupling limit. The fact that the holes undress completely and propagate as free electrons implies there is no relaxation of the charge cloud as depicted in (b), rather the propagation is as depicted in (a), with the holes occupying the lower atomic energy level.

Consider a pair of holes propagating within this model in the limit where the size of the pair is a single lattice spacing. This corresponds to the strong coupling limit where the single hole hopping amplitude goes to zero as discussed in Ref.[41]. In Fig. 10 we show two possible ways the pair propagation can occur. As in Ref.[40] (Eq. (4)), we assume for simplicity that the bare hopping amplitude is the same between all nearest neighbor orbitals, t . If the propagation is as shown in Fig. 10(b), the electrons in the singly occupied site relax to the lower orbital, and the hopping amplitude is reduced by the overlap matrix element S (Eq. 27(a) of Ref.[40]). Instead, if the propagation is as shown in Fig. 10(a), the hopping amplitude is not reduced. This corresponds to the case where the *holes* occupy the lowest orbital, as depicted on the right side of Fig. 6.

The wavefunction for a pair of holes is a linear combination of the states

$$|\Psi_p\rangle = \frac{1}{\sqrt{N}} \sum_i |\uparrow\downarrow\rangle_i \quad (44a)$$

$$|\Psi_{ex}\rangle = \sqrt{\frac{2}{zN}} \sum_{\langle ij \rangle} [|\uparrow\rangle_i |\downarrow\rangle_j - |\downarrow\rangle_i |\uparrow\rangle_j] \quad (44b)$$

where i, j are nearest neighbor sites and z is the number of nearest neighbors to a site. Its energy is the lowest eigenvalue of the matrix

$$H_1 = \begin{vmatrix} 0 & -2t\sqrt{z} \\ -2t\sqrt{z} & -U' \end{vmatrix}$$

or the matrix

$$H_2 = \begin{vmatrix} 0 & -2tS\sqrt{z} \\ -2tS\sqrt{z} & -U' - 2\epsilon \end{vmatrix}$$

for the case of Fig. 10(a) and 10(b) respectively. In the limit where S is very small, the condition on the

parameters for the lowest eigenvalue of H_1 to be smaller than the lowest eigenvalue of H_2 is

$$\sqrt{z}t > \sqrt{\frac{\epsilon U'}{2} + \epsilon^2} \quad (45)$$

Here, t is the bare electron hopping amplitude for an empty band. For a cubic lattice it is given by

$$t = \frac{\hbar^2}{2m_e a^2} = \frac{3.81eV}{a(\text{\AA})^2} \quad (46)$$

Therefore, the condition Eq. (45) can be satisfied for reasonable parameters, e.g. $a = 2\text{\AA}$, $t = 0.95eV$, $\epsilon = 1eV$, $U' = 5eV$. In that case, the hole propagates without disturbing the background, as shown schematically in the left diagram of Fig. 7. The propagation shown in Fig. 10(b) corresponds to ‘partial’ undressing from the electron-electron interaction, while that shown in Fig. 10(a) corresponds to full undressing

VIII. DISCUSSION

In this paper we have discussed the point of view that the competition between electron-ion interaction dominance versus electron-electron interaction dominance in solids leads to normal metallic or superconducting behavior depending on whether the former or the latter wins. Electron-electron interaction will dominate when an electronic energy band is almost full, i.e. when the carriers in the normal state are hole-like. Correspondingly, superconductors in nature are found to have positive Hall coefficient in the normal state[35]. Furthermore, the electron-electron interaction strength e^2 will dominate over the electron-ion interaction strength Ze^2 when the ionic charge Z is small. Correspondingly, high T_c superconductivity is found in materials with highly negatively charged substructures (planes) containing negative ions, like the $(Cu - O_2)^-$ planes in the cuprates, the $(Fe - As)^-$ planes in the arsenides and the B^- planes in MgB_2 .

Here we restricted the discussion of the atom and the diatomic molecule to the simplest case of a $1s$ orbital. However exactly the same physics should take place in bands originating from other atomic orbitals. For example we showed in Ref.[19] that the quantities of interest for $2p$ orbitals in a diatomic molecule behave very similarly to those in the $1s$ orbital. With p orbitals, the roles of $k \sim 0$ and $k \sim \pi$ switch, however the essential physics determined by whether a state is near the bottom or near the top of the band remains the same.

When one talks about electronic energy bands one is implicitly privileging the electron-ion interaction over the electron-electron interaction. The states at the bottom of a band have low electron-ion energy, and those at the top of a band have high electron-ion energy. However, conversely, as we have argued in this paper, electrons residing in states near the bottom of the band have high

electron-electron repulsion energy, and those near the top of the band have low electron-electron repulsion energy. It is only natural to assume that in certain cases a complete reorganization can occur and a new state will emerge that optimizes the electron-electron interaction instead of the electron-ion interaction. That, we propose, is the superconducting state: electrons redistribute their occupation in the band states to occupy the high electron-ion energy states, low electron-electron energy states, and leave empty the low electron-ion energy states, high electron-electron energy states. The concept of “holes” provides a natural language to describe the process: holes condense to occupy the low electron-ion states, giving rise to hole superconductivity.

The physics proposed in this paper also illustrates an even closer connection between the phenomena of superconductivity and metallic ferromagnetism than previously suspected[42]. In our previous work we proposed that both phenomena originate in electronic “bond charge repulsion”[15, 43, 44], both lead to lowering of the carrier effective mass[23, 45] and “undressing”[22, 46], and both are driven by off-diagonal matrix elements of the Coulomb interaction[47], with ferromagnetism dominating near the half-filled band[14] and superconductivity when the band is almost full. For metallic ferromagnetism it was always clear that the phenomenon involves occupying some states that are unfavorable for the electron-ion interaction and emptying some states that are favorable to the electron-ion interaction. Namely, the majority spin electrons occupy antibonding states that were empty in the non-ferromagnetic state, and some bonding states that were occupied by the minority spins in the normal state become empty in the ferromagnetic state[14]. With the interpretation of superconductivity proposed in this paper it is clear that something quite similar occurs in the superconducting state, with empty antibonding states becoming full and full bonding states becoming empty.

In previous work we have emphasized the contribution to Δt arising solely from modulation of the single

particle hopping amplitude by the on-site orbital expansion overlap matrix elements (Frank-Condon factor)[1]. That physics is contained in the ‘dynamic Hubbard model’[48] with an on-site Coulomb repulsion modulated by a local boson degree of freedom, or in a purely electronic model with two orbitals per site and only on-site interactions[40]. These models have much of the relevant physics: they give rise to pairing and superconductivity driven by “undressing” from the electron-electron interaction[49, 50]. However these models don’t allow for a change in sign of the single particle hopping amplitude, thus will not lead to “undressing” from the electron-ion interaction. That physics requires inclusion of off-site Coulomb matrix elements in the Hamiltonian as discussed in Sect. III.

In summary, in this paper we have proposed a new physical picture to describe superconductors: that it is the *holes* that condense to the bottom of the electronic energy band when a system becomes superconducting. This naturally ties together several elements introduced earlier within the theory of hole superconductivity: it explains why carriers undress from the electron-electron and the electron-ion interactions and behave as completely free electrons, yet their *number* is the number of holes rather than the number of electrons in the band; the physics is tied to the Coulomb matrix element Δt that has played a key role since the beginnings of this theory[15]; finally, we have shown that this physics is connected to the negative charge expulsion from the interior of superconductors previously found based on different arguments[26].

In a finite cluster, this reorganization of energy level occupation should also occur, amongst the discrete energy levels of the cluster. It has not escaped our notice that this may provide an explanation for the remarkable experimental observations of de Heer and coworkers[51].

Further discussion and development of this physics and its connection with other elements of the theory will be given in future work.

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